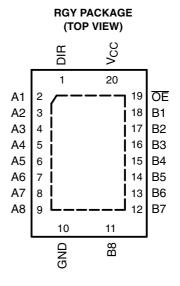
- Supports Mixed-Mode Signal Operation (5-V Input and Output Voltages With 3.3-V V_{CC})
- Supports Unregulated Battery Operation Down to 2.7 V
- Typical V_{OLP} (Output Ground Bounce)
 <0.8 V at V_{CC} = 3.3 V, T_A = 25°C

| DIR 1 20 V _{CC} A1 2 19 OE A2 3 18 B1 | DB, DW, NS, OR PW PACKAGE (TOP VIEW) | | | | | | | | | |
|--|---|---|--|--|--|--|--|--|--|--|
| A3 [] 4 17]] B2 A4 [] 5 16]] B3 A5 [] 6 15]] B4 A6 [] 7 14]] B5 A7 [] 8 13]] B6 A8 [] 9 12]] B7 GND [] 10 11]] B8 | DIR [A1 [A2 [A3 [A4 [A5 [A7 [A8 [| 1 2 3 4 5 6 7 8 9 | 20 19 18 17 16 15 14 13 | OE B1 B2 B3 B4 B5 B6 | | | | | | |

- I_{off} and Power-Up 3-State Support Hot Insertion
- Latch-Up Performance Exceeds 100 mA Per JESD 78, Class II
- ESD Protection Exceeds JESD 22
 - 2000-V Human-Body Model (A114-A)
 - 200-V Machine Model (A115-A)
 - 1000-V Charged-Device Model (C101)



description/ordering information

This octal bus transceiver is designed specifically for low-voltage (3.3-V) V_{CC} operation, but with the capability to provide a TTL interface to a 5-V system environment.

The SN74LVT245B is designed for asynchronous communication between data buses. The device transmits data from the A bus to the B bus or from the B bus to the A bus, depending on the logic level at the direction-control (DIR) input. The output-enable (\overline{OE}) input can be used to disable the device so the buses are effectively isolated.

| | • • • • • • • | | | |
|----------------|-----------------------|---------------|--------------------------|---------------------|
| T _A | PACKAGE | t | ORDERABLE PART NUMBER | TOP-SIDE MARKING |
| | QFN – RGY | Tape and reel | SN74LVT245BRGYR | LX245B |
| | | Tube | SN74LVT245BDW | |
| | SOIC – DW | Tape and reel | SN74LVT245BDWR | LVT245B |
| | SOP – NS | Tape and reel | SN74LVT245BNSR | LVT245B |
| –40°C to 85°C | SSOP – DB | Tape and reel | SN74LVT245BDBR | LX245B |
| | T0000 DW/ | Tube | SN74LVT245BPW | |
| | TSSOP – PW | Tape and reel | SN74LVT245BPWR | LX245B |
| | VFBGA – GQN | Tana and real | SN74LVT245BGQNR | |
| | VFBGA – ZQN (Pb-free) | Tape and reel | SN74LVT245BZQNR | LX245B |

ORDERING INFORMATION

[†] Package drawings, standard packing quantities, thermal data, symbolization, and PCB design guidelines are available at www.ti.com/sc/package.

Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.

PRODUCTION DATA information is current as of publication date. Products conform to specifications per the terms of Texas Instruments standard warranty. Production processing does not necessarily include testing of all parameters.



Copyright © 2003, Texas Instruments Incorporated

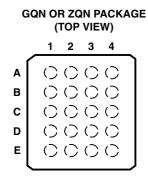
1

SCES004H - JANUARY 1995 - REVISED SEPTEMBER 2003

description/ordering information (continued)

To ensure the high-impedance state during power up or power down, $\overline{\text{OE}}$ should be tied to V_{CC} through a pullup resistor; the minimum value of the resistor is determined by the current-sinking capability of the driver.

This device is fully specified for hot-insertion applications using Ioff and power-up 3-state. The Ioff circuitry disables the outputs, preventing damaging current backflow through the device when it is powered down. The power-up 3-state circuitry places the outputs in the high-impedance state during power up and power down, which prevents driver conflict.



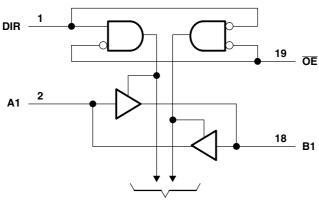
terminal assignments

| | 1 | 2 | 3 | 4 | |
|---|-----|-----|-----------------|----|--|
| Α | A1 | DIR | V _{CC} | ŌĒ | |
| в | A3 | B2 | A2 | B1 | |
| С | A5 | A4 | B4 | B3 | |
| D | A7 | B6 | A6 | B5 | |
| Е | GND | A8 | B8 | B7 | |

FUNCTION TABLE

| INP | UTS | | | | | |
|-----|-----|-----------------|--|--|--|--|
| ŌE | DIR | OPERATION | | | | |
| L | L | B data to A bus | | | | |
| L | Н | A data to B bus | | | | |
| Н | Х | Isolation | | | | |

logic diagram (positive logic)



To Seven Other Channels

Pin numbers shown are for the DB, DW, NS, PW, and RGY packages.



SCES004H - JANUARY 1995 - REVISED SEPTEMBER 2003

absolute maximum ratings over operating free-air temperature range (unless otherwise noted)[†]

| Supply voltage range, V _{CC} | -0.5 V to 4.6 V |
|---|-----------------|
| Input voltage range, $V_{\rm I}$ (see Note 1) | |
| Voltage range applied to any output in the high-impedance | |
| or power-off state, V_{Ω} (see Note 1) | –0.5 V to 7 V |
| Voltage range applied to any output in the high state, V_O (see Note 1) | |
| Current into any output in the low state, I_0 | |
| Current into any output in the high state, I _O (see Note 2) | |
| Input clamp current, I_{IK} (V _I < 0) | |
| Output clamp current, I_{OK} ($V_O < 0$) | |
| Package thermal impedance, θ_{JA} (see Note 3): DB package | |
| (see Note 3): DW package | |
| (see Note 3): GQN/ZQN package | |
| (see Note 3): NS package | |
| (see Note 3): PW package | |
| (see Note 4): RGY package | |
| Storage temperature range, T _{sta} | |
| | |

[†] Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

NOTES: 1. The input and output negative-voltage ratings may be exceeded if the input and output clamp-current ratings are observed.

- 2. This current flows only when the output is in the high state and $V_{O} > V_{CC}$.
- 3. The package thermal impedance is calculated in accordance with JESD 51-7.
- 4. The package thermal impedance is calculated in accordance with JESD 51-5.

recommended operating conditions (see Note 5)

| | | | MIN | МАХ | UNIT |
|----------------------------|------------------------------------|-----------------|-----|-----|------|
| V _{CC} | Supply voltage | | 2.7 | 3.6 | V |
| V _{IH} | High-level input voltage | | 2 | | V |
| V _{IL} | Low-level input voltage | | | 0.8 | V |
| VI | Input voltage | | | 5.5 | V |
| I _{OH} | High-level output current | | | | mA |
| I _{OL} | Low-level output current | | | 64 | mA |
| $\Delta t / \Delta v$ | Input transition rise or fall rate | Outputs enabled | | 10 | ns/V |
| $\Delta t / \Delta V_{CC}$ | Power-up ramp rate | | 200 | | μs/V |
| T _A | Operating free-air temperature | | -40 | 85 | °C |

NOTE 5: All unused inputs of the device must be held at V_{CC} or GND to ensure proper device operation. Refer to the TI application report, Implications of Slow or Floating CMOS Inputs, literature number SCBA004.



SCES004H - JANUARY 1995 - REVISED SEPTEMBER 2003

electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

| | PARAMETER | TES | T CONDITIONS | MIN | TYP [†] | MAX | UNIT |
|---------------------------|-------------------------|---|--------------------------------------|----------------------|------------------|------|------|
| V _{IK} | | V _{CC} = 2.7 V, | I _I = -18 mA | | | -1.2 | V |
| | | V _{CC} = 2.7 V to 3.6 V, | I _{OH} = −100 μA | V _{CC} -0.2 | | | |
| V _{OH} | | V _{CC} = 2.7 V, | I _{OH} = -8 mA | 2.4 | | | v |
| | | V _{CC} = 3 V, | I _{OH} = -32 mA | 2 | | | |
| | | V 07V | I _{OL} = 100 μA | | | 0.2 | |
| | | $V_{CC} = 2.7 V$ | I _{OL} = 24 mA | | | 0.5 | |
| V _{OL} | | I _{OL} = 16 mA | | | | | |
| | | $V_{CC} = 3 V$ | I _{OL} = 32 mA | | | 0.5 | |
| | | | I _{OL} = 64 mA | | | 0.55 | |
| | Quatastinants | V _{CC} = 3.6 V, | $V_I = V_{CC}$ or GND | | ±1 | :1 | |
| | Control inputs | $V_{CC} = 0 \text{ or } 3.6 \text{ V},$ | V _I = 5.5 V | | | 10 | |
| l _i | li | | V _I = 5.5 V | | | 20 | μA |
| A or B ports [‡] | V _{CC} = 3.6 V | $V_I = V_{CC}$ | | 1 | | | |
| | | | $V_{I} = 0$ | -5 | | | |
| I _{off} | | $V_{CC} = 0,$ | V_{I} or $V_{O} = 0$ to 4.5 V | | | ±100 | μA |
| I _{OZH} | | V _{CC} = 3.6 V, | V _O = 3 V | | | 5 | μA |
| I _{OZL} | | V _{CC} = 3.6 V, | V _O = 0.5 V | | | -5 | μA |
| I _{OZPU} | | V_{CC} = 0 to 1.5 V, V_O = 0.5 V | to 3 V, \overline{OE} = don't care | | | ±100 | μA |
| I _{OZPD} | | V_{CC} = 1.5 V to 0, V_{O} = 0.5 V | to 3 V, \overline{OE} = don't care | | | ±100 | μA |
| | | V _{CC} = 3.6 V, | Outputs high | | | 0.19 | |
| I _{CC} | | $I_{O} = 0,$ | Outputs low | | 5 | | mA |
| | | $V_I = V_{CC}$ or GND | Outputs disabled | 0.19 | | | |
| ∆l _{CC} § | | V_{CC} = 3 V to 3.6 V, One input Other inputs at V_{CC} or GND | | | | | mA |
| Ci | | V _I = 3 V or 0 | | | | | pF |
| Cio | | V _O = 3 V or 0 | | | 9 | | pF |

 † All typical values are at V_{CC} = 3.3 V, T_A = 25°C.

[‡] Unused terminals are at V_{CC} or GND.

§ This is the increase in supply current for each input that is at the specified TTL-voltage level, rather than V_{CC} or GND.

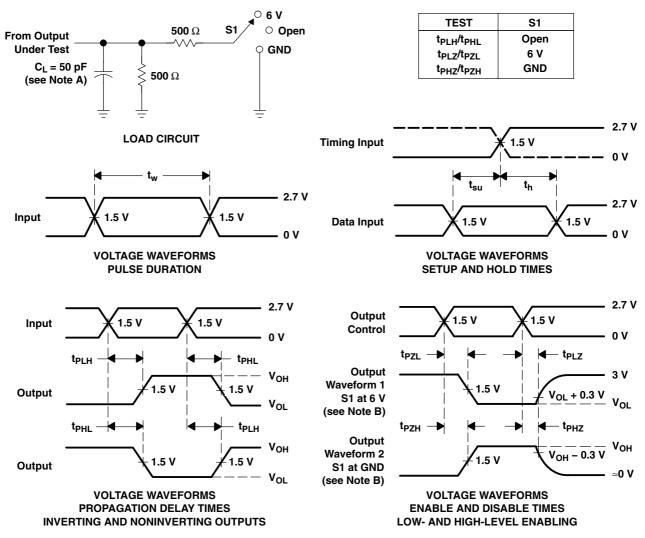
switching characteristics over recommended operating free-air temperature range, C_L = 50 pF (unless otherwise noted) (see Figure 1)

| PARAMETER | FROM | TO | vo | _{CC} = 3.3 ' ± 0.3 V | V | V _{CC} = | UNIT | |
|------------------|-----------|----------|-----|----------------------------------|-----|-------------------|------|----|
| | (INPUT) | (OUTPUT) | MIN | TYP [†] | MAX | MIN | MAX | |
| t _{PLH} | | D er A | 1.2 | 2.3 | 3.5 | | 4 | |
| t _{PHL} | A or B | B or A | 1.2 | 2.1 | 3.5 | | 4 | ns |
| t _{PZH} | <u>AE</u> | A as D | 1.3 | 3.2 | 5.5 | | 7.1 | |
| t _{PZL} | ŌĒ | A or B | 1.7 | 3.4 | 5.5 | | 6.5 | ns |
| t _{PHZ} | <u>AE</u> | A ar D | 2.2 | 3.5 | 5.9 | | 6.5 | |
| t _{PLZ} | ŌĒ | A or B | 2.2 | 3.4 | 5 | | 5.1 | ns |

 † All typical values are at V_{CC} = 3.3 V, T_A = 25°C.



SCES004H - JANUARY 1995 - REVISED SEPTEMBER 2003



PARAMETER MEASUREMENT INFORMATION

NOTES: A. CL includes probe and jig capacitance.

- B. Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high except when disabled by the output control.
- C. All input pulses are supplied by generators having the following characteristics: PRR \leq 10 MHz, Z_O = 50 Ω , t_f \leq 2.5 ns, t_f \leq 2.5 ns.
- D. The outputs are measured one at a time with one transition per measurement.
- E. All parameters and waveforms are not applicable to all devices.

Figure 1. Load Circuit and Voltage Waveforms





10-Dec-2020

PACKAGING INFORMATION

| Orderable Device | Status (1) | Package Type | Package Drawing | Pins | Package Qty | Eco Plan (2) | Lead finish/ Ball material | MSL Peak Temp (3) | Op Temp (°C) | Device Marking (4/5) | Samples |
|------------------|---------------|--------------|--------------------|------|----------------|-----------------|-------------------------------|----------------------|--------------|-------------------------|---------|
| SN74LVT245BDBR | ACTIVE | SSOP | DB | 20 | 2000 | RoHS & Green | NIPDAU | Level-1-260C-UNLIM | -40 to 85 | LX245B | Samples |
| SN74LVT245BDBRE4 | ACTIVE | SSOP | DB | 20 | 2000 | RoHS & Green | NIPDAU | Level-1-260C-UNLIM | -40 to 85 | LX245B | Samples |
| SN74LVT245BDW | ACTIVE | SOIC | DW | 20 | 25 | RoHS & Green | NIPDAU | Level-1-260C-UNLIM | -40 to 85 | LVT245B | Samples |
| SN74LVT245BDWE4 | ACTIVE | SOIC | DW | 20 | 25 | RoHS & Green | NIPDAU | Level-1-260C-UNLIM | -40 to 85 | LVT245B | Samples |
| SN74LVT245BDWG4 | ACTIVE | SOIC | DW | 20 | 25 | RoHS & Green | NIPDAU | Level-1-260C-UNLIM | -40 to 85 | LVT245B | Samples |
| SN74LVT245BDWR | ACTIVE | SOIC | DW | 20 | 2000 | RoHS & Green | NIPDAU | Level-1-260C-UNLIM | -40 to 85 | LVT245B | Samples |
| SN74LVT245BDWRE4 | ACTIVE | SOIC | DW | 20 | 2000 | RoHS & Green | NIPDAU | Level-1-260C-UNLIM | -40 to 85 | LVT245B | Samples |
| SN74LVT245BNSR | ACTIVE | SO | NS | 20 | 2000 | RoHS & Green | NIPDAU | Level-1-260C-UNLIM | -40 to 85 | LVT245B | Samples |
| SN74LVT245BPW | ACTIVE | TSSOP | PW | 20 | 70 | RoHS & Green | NIPDAU | Level-1-260C-UNLIM | -40 to 85 | LX245B | Samples |
| SN74LVT245BPWG4 | ACTIVE | TSSOP | PW | 20 | 70 | RoHS & Green | NIPDAU | Level-1-260C-UNLIM | -40 to 85 | LX245B | Samples |
| SN74LVT245BPWR | ACTIVE | TSSOP | PW | 20 | 2000 | RoHS & Green | NIPDAU | Level-1-260C-UNLIM | -40 to 85 | LX245B | Samples |
| SN74LVT245BPWRE4 | ACTIVE | TSSOP | PW | 20 | 2000 | RoHS & Green | NIPDAU | Level-1-260C-UNLIM | -40 to 85 | LX245B | Samples |
| SN74LVT245BPWRG4 | ACTIVE | TSSOP | PW | 20 | 2000 | RoHS & Green | NIPDAU | Level-1-260C-UNLIM | -40 to 85 | LX245B | Samples |
| SN74LVT245BRGYR | ACTIVE | VQFN | RGY | 20 | 3000 | RoHS & Green | NIPDAU | Level-2-260C-1 YEAR | -40 to 85 | LX245B | Samples |

⁽¹⁾ The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

⁽²⁾ RoHS: TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".



PACKAGE OPTION ADDENDUM

10-Dec-2020

RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption. **Green:** TI defines "Green" to mean the content of Chlorine (CI) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

⁽³⁾ MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

⁽⁴⁾ There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

⁽⁵⁾ Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

⁽⁶⁾ Lead finish/Ball material - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

Important Information and Disclaimer: The information provided on this page represents TI's knowledge and belief as of the date that it is provided. TI bases its knowledge and belief on information provided by third parties, and makes no representation or warranty as to the accuracy of such information. Efforts are underway to better integrate information from third parties. TI has taken and continues to take reasonable steps to provide representative and accurate information but may not have conducted destructive testing or chemical analysis on incoming materials and chemicals. TI and TI suppliers consider certain information to be proprietary, and thus CAS numbers and other limited information may not be available for release.

In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.



Texas

STRUMENTS

TAPE AND REEL INFORMATION





QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



| Device | Package Type | Package Drawing | | SPQ | Reel Diameter (mm) | Reel Width W1 (mm) | A0 (mm) | B0 (mm) | K0 (mm) | P1 (mm) | W (mm) | Pin1 Quadrant |
|-----------------|-----------------|--------------------|----|------|--------------------------|--------------------------|------------|------------|------------|------------|-----------|------------------|
| SN74LVT245BDBR | SSOP | DB | 20 | 2000 | 330.0 | 16.4 | 8.2 | 7.5 | 2.5 | 12.0 | 16.0 | Q1 |
| SN74LVT245BDWR | SOIC | DW | 20 | 2000 | 330.0 | 24.4 | 10.8 | 13.3 | 2.7 | 12.0 | 24.0 | Q1 |
| SN74LVT245BNSR | SO | NS | 20 | 2000 | 330.0 | 24.4 | 8.4 | 13.0 | 2.5 | 12.0 | 24.0 | Q1 |
| SN74LVT245BPWR | TSSOP | PW | 20 | 2000 | 330.0 | 16.4 | 6.95 | 7.0 | 1.4 | 8.0 | 16.0 | Q1 |
| SN74LVT245BRGYR | VQFN | RGY | 20 | 3000 | 330.0 | 12.4 | 3.8 | 4.8 | 1.6 | 8.0 | 12.0 | Q1 |



www.ti.com

PACKAGE MATERIALS INFORMATION

3-Jun-2022



*All dimensions are nominal

| Device | Package Type | Package Drawing | Pins | SPQ | Length (mm) | Width (mm) | Height (mm) |
|-----------------|--------------|-----------------|------|------|-------------|------------|-------------|
| SN74LVT245BDBR | SSOP | DB | 20 | 2000 | 356.0 | 356.0 | 35.0 |
| SN74LVT245BDWR | SOIC | DW | 20 | 2000 | 367.0 | 367.0 | 45.0 |
| SN74LVT245BNSR | SO | NS | 20 | 2000 | 367.0 | 367.0 | 45.0 |
| SN74LVT245BPWR | TSSOP | PW | 20 | 2000 | 356.0 | 356.0 | 35.0 |
| SN74LVT245BRGYR | VQFN | RGY | 20 | 3000 | 356.0 | 356.0 | 35.0 |

TEXAS INSTRUMENTS

www.ti.com

3-Jun-2022

TUBE



- B - Alignment groove width

*All dimensions are nominal

| Device | Package Name | Package Type | Pins | SPQ | L (mm) | W (mm) | Τ (μm) | B (mm) |
|-----------------|--------------|--------------|------|-----|--------|--------|--------|--------|
| SN74LVT245BDW | DW | SOIC | 20 | 25 | 507 | 12.83 | 5080 | 6.6 |
| SN74LVT245BDWE4 | DW | SOIC | 20 | 25 | 507 | 12.83 | 5080 | 6.6 |
| SN74LVT245BDWG4 | DW | SOIC | 20 | 25 | 507 | 12.83 | 5080 | 6.6 |
| SN74LVT245BPW | PW | TSSOP | 20 | 70 | 530 | 10.2 | 3600 | 3.5 |
| SN74LVT245BPWG4 | PW | TSSOP | 20 | 70 | 530 | 10.2 | 3600 | 3.5 |

PW0020A



PACKAGE OUTLINE

TSSOP - 1.2 mm max height

SMALL OUTLINE PACKAGE



NOTES:

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M. 2. This drawing is subject to change without notice. 3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
- exceed 0.15 mm per side.
- 4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm per side.
- 5. Reference JEDEC registration MO-153.



PW0020A

EXAMPLE BOARD LAYOUT

TSSOP - 1.2 mm max height

SMALL OUTLINE PACKAGE



NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



PW0020A

EXAMPLE STENCIL DESIGN

TSSOP - 1.2 mm max height

SMALL OUTLINE PACKAGE



NOTES: (continued)

- 8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 9. Board assembly site may have different recommendations for stencil design.



LAND PATTERN DATA



NOTES: Α. All linear dimensions are in millimeters.

- B. This drawing is subject to change without notice.
 C. Publication IPC-7351 is recommended for alternate design.
- D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC-7525 for other stencil recommendations.
- E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.



DB0020A



PACKAGE OUTLINE

SSOP - 2 mm max height

SMALL OUTLINE PACKAGE



NOTES:

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M. 2. This drawing is subject to change without notice. 3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
- exceed 0.15 mm per side.
- 4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm per side.
- 5. Reference JEDEC registration MO-150.



DB0020A

EXAMPLE BOARD LAYOUT

SSOP - 2 mm max height

SMALL OUTLINE PACKAGE



NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



DB0020A

EXAMPLE STENCIL DESIGN

SSOP - 2 mm max height

SMALL OUTLINE PACKAGE



NOTES: (continued)

- 8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 9. Board assembly site may have different recommendations for stencil design.



MECHANICAL DATA

PLASTIC SMALL-OUTLINE PACKAGE

0,51 0,35 ⊕0,25⊛ 1,27 8 14 0,15 NOM 5,60 8,20 5,00 7,40 \bigcirc Gage Plane ₽ 0,25 7 1 1,05 0,55 0°-10° Δ 0,15 0,05 Seating Plane — 2,00 MAX 0,10PINS ** 14 16 20 24 DIM 10,50 10,50 12,90 15,30 A MAX A MIN 9,90 9,90 12,30 14,70 4040062/C 03/03

NOTES: A. All linear dimensions are in millimeters.

NS (R-PDSO-G**)

14-PINS SHOWN

- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion, not to exceed 0,15.



GENERIC PACKAGE VIEW

VQFN - 1 mm max height

PLASTIC QUAD FGLATPACK - NO LEAD

3.5 x 4.5, 0.5 mm pitch

RGY 20

This image is a representation of the package family, actual package may vary. Refer to the product data sheet for package details.





4225264/A

RGY0020A



PACKAGE OUTLINE

VQFN - 1 mm max height

PLASTIC QUAD FLATPACK - NO LEAD



NOTES:

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M. 2. This drawing is subject to change without notice.
- 3. The package thermal pad must be soldered to the printed circuit board for thermal and mechanical performance.



RGY0020A

EXAMPLE BOARD LAYOUT

VQFN - 1 mm max height

PLASTIC QUAD FLATPACK - NO LEAD



NOTES: (continued)

4. This package is designed to be soldered to a thermal pad on the board. For more information, see Texas Instruments literature number SLUA271 (www.ti.com/lit/slua271).

5. Vias are optional depending on application, refer to device data sheet. If any vias are implemented, refer to their locations shown on this view. It is recommended that vias under paste be filled, plugged or tented.



RGY0020A

EXAMPLE STENCIL DESIGN

VQFN - 1 mm max height

PLASTIC QUAD FLATPACK - NO LEAD



NOTES: (continued)

6. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.



DW0020A



PACKAGE OUTLINE

SOIC - 2.65 mm max height

SOIC



NOTES:

- 1. All linear dimensions are in millimeters. Dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M. 2. This drawing is subject to change without notice. 3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
- exceed 0.15 mm per side.
- 4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.43 mm per side.
- 5. Reference JEDEC registration MS-013.



DW0020A

EXAMPLE BOARD LAYOUT

SOIC - 2.65 mm max height

SOIC



NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



DW0020A

EXAMPLE STENCIL DESIGN

SOIC - 2.65 mm max height

SOIC



NOTES: (continued)

- 8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 9. Board assembly site may have different recommendations for stencil design.



IMPORTANT NOTICE AND DISCLAIMER

TI PROVIDES TECHNICAL AND RELIABILITY DATA (INCLUDING DATA SHEETS), DESIGN RESOURCES (INCLUDING REFERENCE DESIGNS), APPLICATION OR OTHER DESIGN ADVICE, WEB TOOLS, SAFETY INFORMATION, AND OTHER RESOURCES "AS IS" AND WITH ALL FAULTS, AND DISCLAIMS ALL WARRANTIES, EXPRESS AND IMPLIED, INCLUDING WITHOUT LIMITATION ANY IMPLIED WARRANTIES OF MERCHANTABILITY, FITNESS FOR A PARTICULAR PURPOSE OR NON-INFRINGEMENT OF THIRD PARTY INTELLECTUAL PROPERTY RIGHTS.

These resources are intended for skilled developers designing with TI products. You are solely responsible for (1) selecting the appropriate TI products for your application, (2) designing, validating and testing your application, and (3) ensuring your application meets applicable standards, and any other safety, security, regulatory or other requirements.

These resources are subject to change without notice. TI grants you permission to use these resources only for development of an application that uses the TI products described in the resource. Other reproduction and display of these resources is prohibited. No license is granted to any other TI intellectual property right or to any third party intellectual property right. TI disclaims responsibility for, and you will fully indemnify TI and its representatives against, any claims, damages, costs, losses, and liabilities arising out of your use of these resources.

TI's products are provided subject to TI's Terms of Sale or other applicable terms available either on ti.com or provided in conjunction with such TI products. TI's provision of these resources does not expand or otherwise alter TI's applicable warranties or warranty disclaimers for TI products.

TI objects to and rejects any additional or different terms you may have proposed.

Mailing Address: Texas Instruments, Post Office Box 655303, Dallas, Texas 75265 Copyright © 2022, Texas Instruments Incorporated